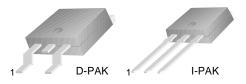


### **KSH45H11**

# General Purpose Power and Switching Such as Output or Driver Stages in Applications D-PAK for Surface Mount Applications

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular KSE45H
- Fast Switching Speeds
- Low Collector Emitter Saturation Voltage



1.Base 2.Collector 3.Emitter

## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| $V_{CEO}$        | Collector-Emitter Voltage                    | - 80       | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | - 5        | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | - 8        | Α     |
| I <sub>CP</sub>  | Collector Current (Pulse)                    | - 16       | Α     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 20         | W     |
|                  | Collector Dissipation (T <sub>a</sub> =25°C) | 1.75       | W     |
| TJ               | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 55 ~ 150 | °C    |

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                 | Parameter                            | Test Condition                    | Min. | Тур. | Max.  | Units |
|------------------------|--------------------------------------|-----------------------------------|------|------|-------|-------|
| V <sub>CEO</sub> (sus) | Collector-Emitter Sustaining Voltage | $I_C = -30 \text{mA}, I_B = 0$    | - 80 |      |       | V     |
| I <sub>CEO</sub>       | Collector Cut-off Current            | $V_{CE} = -80V, I_{B} = 0$        |      |      | - 10  | μΑ    |
| I <sub>EBO</sub>       | Emitter Cut-off Current              | $V_{BE} = -5V, I_{C} = 0$         |      |      | - 50  | μΑ    |
| h <sub>FE</sub>        | DC Current Gain                      | $V_{CE} = -1V, I_{C} = -2A$       | 60   |      |       |       |
|                        |                                      | $V_{CE} = -1V, I_{C} = -4A$       | 40   |      |       |       |
| V <sub>CE</sub> (sat)  | Collector-Emitter Saturation Voltage | $I_C = -8A, I_B = -0.4A$          |      |      | - 1   | V     |
| V <sub>BE</sub> (on)   | Base-Emitter Saturation Voltage      | $I_C = -8A, I_B = -0.8A$          |      |      | - 1.5 | V     |
| f <sub>T</sub>         | Current Gain Bandwidth Product       | $V_{CE} = -10A, I_{C} = -0.5A$    |      | 40   |       | MHz   |
| C <sub>ob</sub>        | Collector Capacitance                | V <sub>CB</sub> = - 10V, f = 1MHz |      | 230  |       | pF    |
| t <sub>ON</sub>        | Turn ON Time                         | I <sub>C</sub> = - 5A             |      | 135  |       | ns    |
| t <sub>STG</sub>       | Storage Time                         | $I_{B1} = -I_{B2} = -0.5A$        |      | 500  |       | ns    |
| t <sub>F</sub>         | Fall Time                            |                                   |      | 100  |       | ns    |

<sup>\*</sup> Pulse Test: PW≤300μs, Duty Cycle≤2%

# **Typical Characteristics**

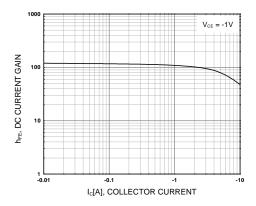


Figure 1. DC current Gain

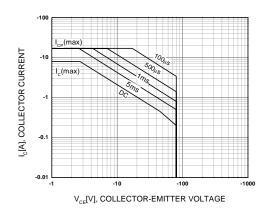


Figure 2. Safe Operating Area

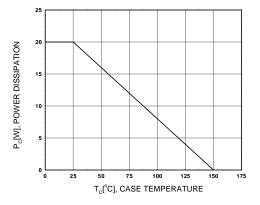
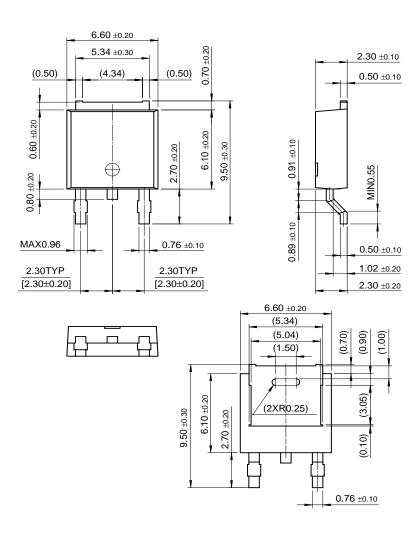


Figure 3. Power Derating

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# **Package Demensions**

# D-PAK



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| CROSSVOLT™           | GlobalOptoisolator™ | Power247™                | SuperSOT™-6           |
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| EnSigna™             | MicroFET™           | Quiet Series™            | UHC™                  |
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